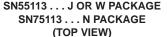
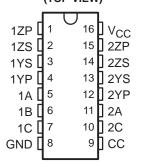
- Choice of Open-Collector, Open-Emitter, or **3-State Outputs**
- **High-Impedance Output State for Party-Line Applications**
- Single-Ended or Differential AND/NAND **Outputs**
- Single 5-V Supply
- **Dual Channel Operation**
- **Compatible With TTL**
- **Short-Circuit Protection**
- **High-Current Outputs**
- **Common and Individual Output Controls**
- **Clamp Diodes at Inputs and Outputs**
- Easily Adaptable to SN55114 and SN75114 **Applications**
- Designed for Use With SN55115 and SN75115

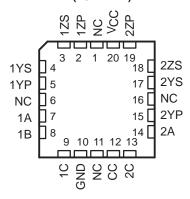
description

The SN55113 and SN75113 dual differential line drivers with 3-state outputs are designed to provide all the features of the SN55114 and SN75114 line drivers with the added feature of driver output controls. Individual controls are provided for each output pair, as well as a common control for both output pairs. If any output





SN55113 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

is low, the associated output is in a high-impedance state and the output can neither drive nor load the bus. This permits many devices to be connected together on the same transmission line for party-line applications.

The output stages are similar to TTL totem-pole outputs, but with the sink outputs, YS and ZS, and the corresponding active pullup terminals, YP and ZP, available on adjacent package pins.

The SN55113 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN75113 is characterized for operation over the temperature range of 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

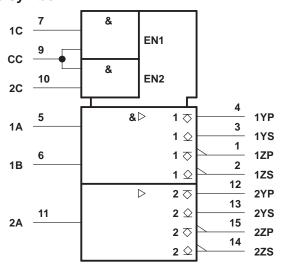


FUNCTION TABLE

	OUTPUTS					
OUTPUT			AND	NAND		
С	CC	CC A		Y	Z	
L	Х	Х	Х	Z	Z	
Х	L	Х	Χ	Z	Z	
Н	Н	L	Χ	L	Н	
Н	Н	Х	L	L	Н	
Н	Н	Н	Н	Н	L	

H = high level, L = low level, X = irrelevant,

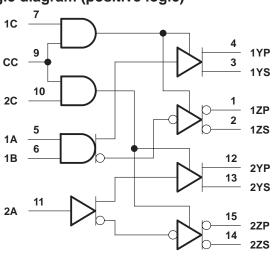
logic symbol‡



[‡] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the J, N, and W packages.

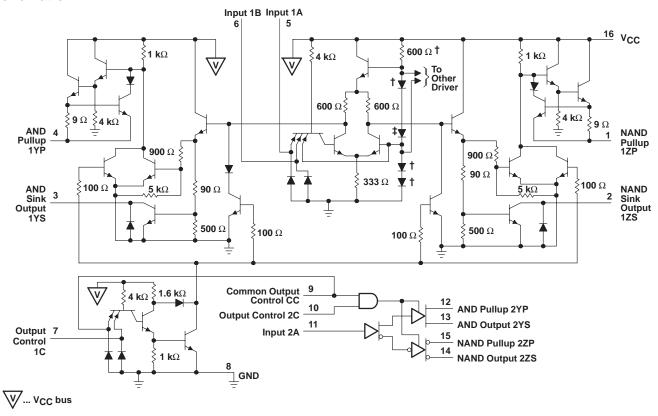
logic diagram (positive logic)



Z = high impedance (off)

[†]B input and 4th line of function table are applicable only to driver number 1.

schematic



[†] These components are common to both drivers. Resistor values shown are nominal and in ohms.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V _{CC} (see Note 1)	7 V
Input voltage, V _I	
Off-state voltage applied to open-collector outputs	12 V
Continuous total power dissipation (see Note 2)	See Dissipation Rating Table
Operating free-air temperature range, T _A : SN55113	–55°C to 125°C
SN75113	0°C to 70°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: N package .	260°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W packa	ge 300°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	N/A
W	1000 mW	8.0 mW/°C	640 mW	200 mW



SN55113, SN75113 **DUAL DIFFERENTIAL LINE DRIVERS**

SLLS070C - SEPTEMBER 1973 - REVISED MARCH 1997

recommended operating conditions

	;	SN55113			SN75113			
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V	
High-level input voltage, VIH	2			2			V	
Low-level input voltage, V _{IL}			8.0			0.8	V	
High-level output current, IOH			- 40			- 40	mA	
Low-level output current, IOL			40			40	mA	
Operating free-air temperature, TA	-55		125	0		70	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED				uo t		SN55113			SN75113		
	PARAMETER		'5	TEST CONDITIONS [†]		MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	UNIT
۷ıĸ	Input clamp vo	ltage	V _{CC} = MIN,	I _I = -12 mA			-0.9	-1.5		-0.9	-1.5	V
V0	High-level outp	out	V _{CC} = MIN,	V _{IH} = 2 V,	$I_{OH} = -10 \text{ mA}$	2.4	3.4		2.4	3.4		V
VOH	voltage		V _{IL} = 0.8 V		$I_{OH} = -40 \text{mA}$	2	3.0		2	3.0		V
VOL	Low-level outp	out	$V_{CC} = MIN,$ $I_{OL} = 40 \text{ mA}$	V _{IH} = 2 V,	V _{IL} = 0.8 V,		0.23	0.4		0.23	0.4	V
Vок	Output clamp	voltage	$V_{CC} = MAX$,	$I_{O} = -40 \text{ mA}$			-1.1	-1.5		-1.1	-1.5	V
			V _{OH} = 12 V	T _A = 25°C		1	10					
10.00	Off-state	autaut	V _{CC} = MAX	VOH = 12 V	T _A = 125°C			200				
^I O(off)	open-collector current	output	ACC = MAX	Va 5 25 V	T _A = 25°C					1	10	μΑ
		v	V _{OH} = 5.25 V	T _A = 70°C						20		
				$T_A = 25^{\circ}C$,	$V_O = 0$ to V_{CC}			±10			±10	
	Off-state (high-impedance-state)		$V_{CC} = MAX$,	T _A = MAX	V _O = 0			-150			-20	μА
loz			Output controls at		$V_0 = 0.4 \text{ V}$			±80			±20	
	output current	itput current 0.8 V		I A - WAX	V _O = 2.4 V			±80			±20	
					AO = ACC			80			20	
.	Input current	A, B, C		\/ E = \/				1			1	^
†¡	at maximum input voltage	СС	$V_{CC} = MAX,$	V _I = 5.5 V				2			2	mA
l	High-level	A, B, C	V _{CC} = MAX, V	\\\ - 2 4 \\				40			40	μА
ΉΗ	input current	CC	VCC = IVIAX,	V = 2.4 V				80			80	μΑ
l	Low-level	A, B, C	V _{CC} = MAX, V _I = 0.4 V					-1.6			-1.6	mA
¹IL	input current	CC	VCC = WAX,	V = 0.4 V				-3.2			-3.2	ША
los	Short-circuit output current	§	V _{CC} = MAX,	V _O = 0,	T _A = 25°C	-40	-90	-120	-40	-90	-120	mA
loo	Supply current	t	All inputs at 0 \	/, No load,	$V_{CC} = MAX$		47	65		47	65	mΛ
ICC	(both drivers)		T _A = 25°C				65	85		65	85	mA

[†] All parameters with the exception of off-state open-collector output current are measured with the active pullup connected to the sink output. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



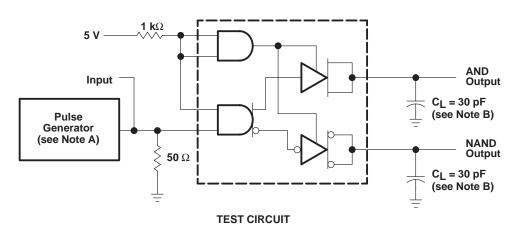
 $[\]ddagger$ All typical values are at TA = 25°C and VCC = 5 V, with the exception of VCC at 7 V.

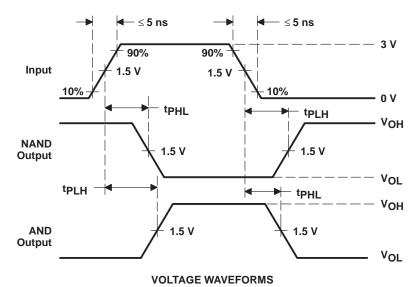
[§] Only one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, C_L = 30 pF, T_A = 25°C

PARAMETER		TEST CONDITIONS	SN55113			SN75113			UNIT
		TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	Olviii
tPLH	Propagation delay time, low-to-high level output	See Figure 1		13	20		13	30	ns
tPHL	Propagation delay time, high-to-low-level output	See Figure 1		12	20		12	30	ns
^t PZH	Output enable time to high level	R_L = 180 Ω, See Figure 2		7	15		7	20	ns
tPZL	Output enable time to low level	R_L = 250 Ω, See Figure 3		14	30		14	40	ns
t _{PHZ}	Output disable time from high level	R_L = 180 Ω, See Figure 2		10	20		10	30	ns
t _{PLZ}	Output disable time from low level	R_L = 250 Ω, See Figure 3		17	35		17	35	ns

PARAMETER MEASUREMENT INFORMATION





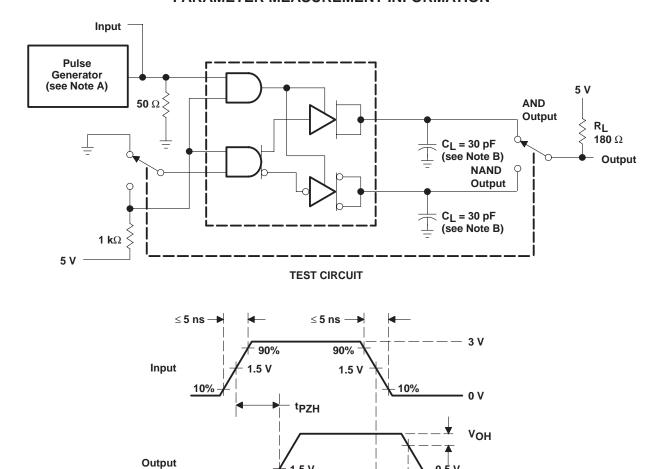
NOTES: A. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, PRR $\leq 500 \text{ kHz}$, $t_W = 100 \text{ ns}$.

B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms t_{PLH} and t_{PHL}



PARAMETER MEASUREMENT INFORMATION



VOLTAGE WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, PRR $\leq 500 \ kHz$, $t_W = 100 \ ns$.

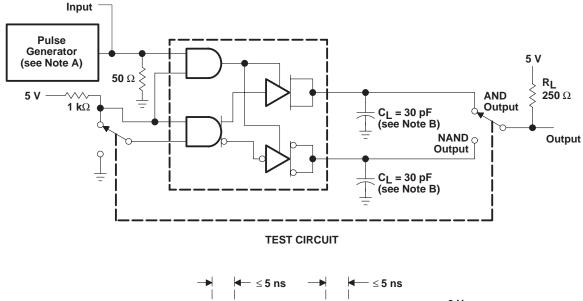
B. C_I includes probe and jig capacitance.

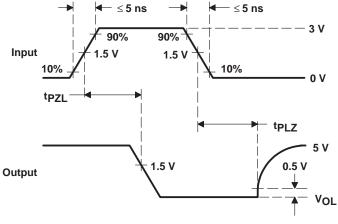
Figure 2. Test Circuit and Voltage Waveforms tpzH and tpHZ

^tPHZ

 $V_{off}\approx 0\ V$

PARAMETER MEASUREMENT INFORMATION





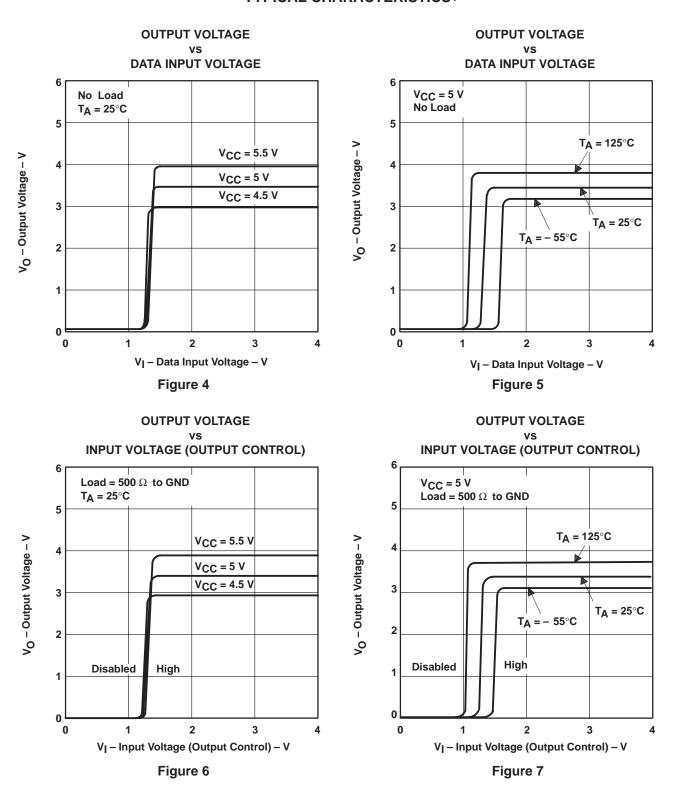
VOLTAGE WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω , PRR \leq 500 kHz, t_W = 100 ns.

B. C_L includes probe and jig capacitance.

Figure 3. Test Circuit and Voltage Waveforms, $t_{\mbox{\scriptsize PZL}}$ and $t_{\mbox{\scriptsize PLZ}}$

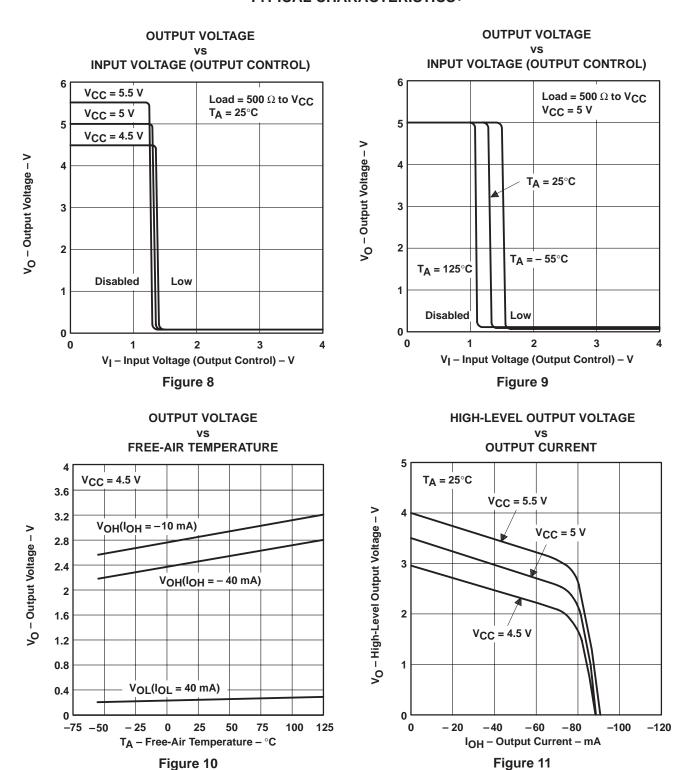
TYPICAL CHARACTERISTICS[†]



[†] Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.



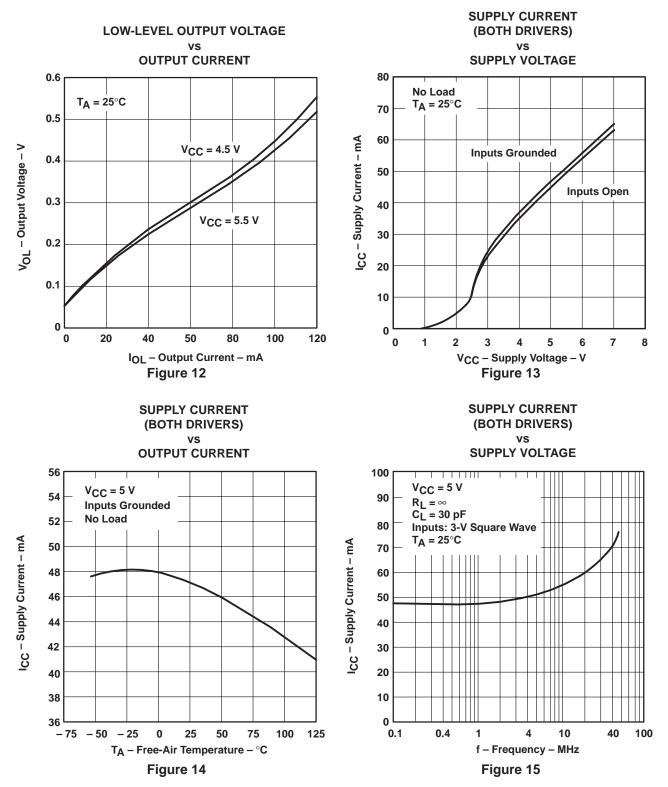
TYPICAL CHARACTERISTICS†



[†] Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.



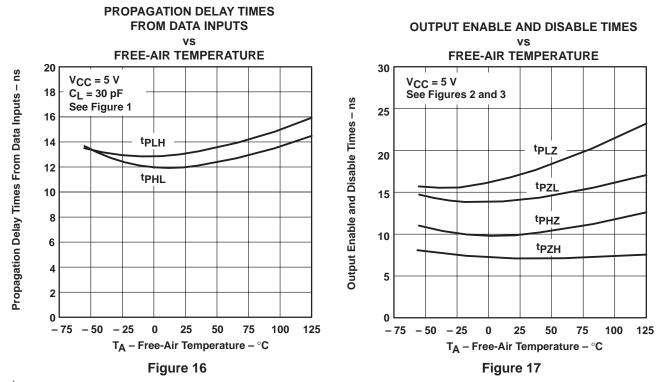
TYPICAL CHARACTERISTICS†



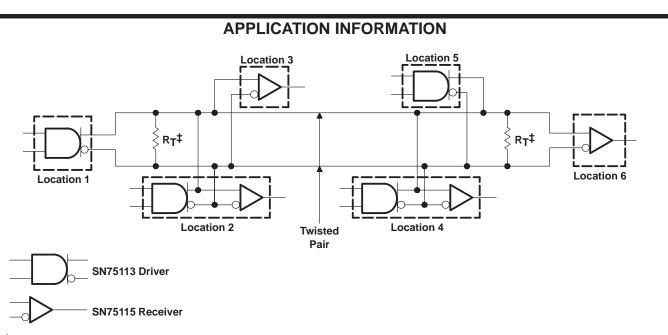
[†] Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.



TYPICAL CHARACTERISTICS[†]



[†] Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.



 $\ddagger R_T = Z_O$. A capacitor may be connected in series with R_T to reduce power dissipation.

Figure 18. Basic Party-Line or Data-Bus Differential Data Transmission



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